



60EPU04
60APU04

Ultrafast Soft Recovery Diode

Features

- Ultrafast Recovery
- 175°C Operating Junction Temperature

Benefits

- Reduced RFI and EMI
- Higher Frequency Operation
- Reduced Snubbing
- Reduced Parts Count

$t_{rr} = 50\text{ns (typ)}$
$I_{F(AV)} = 60\text{Amp}$
$V_R = 400\text{V}$

Description/ Applications


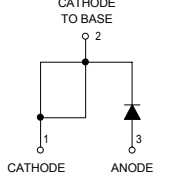

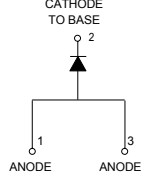
These diodes are optimized to reduce losses and EMI/ RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameters	Max	Units
V_R Cathode to Anode Voltage	400	V
$I_{F(AV)}$ Continuous Forward Current, $T_C = 127^\circ\text{C}$	60	A
I_{FSM} Single Pulse Forward Current, $T_C = 25^\circ\text{C}$	600	
I_{FRM} ① Maximum Repetitive Forward Current	120	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 55 to 175	$^\circ\text{C}$

① Square Wave, 20kHz

Case Styles

<p>60EPU04</p>   <p>CATHODE TO BASE</p> <p>CATHODE ANODE</p> <p>TO-247AC (Modified)</p>	<p>60APU04</p>   <p>CATHODE TO BASE</p> <p>ANODE ANODE</p> <p>TO-247AC</p>
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Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions
V _{BR} , V _r Breakdown Voltage, Blocking Voltage	400	-	-	V	I _R = 100μA
V _F Forward Voltage	-	1.05	1.25	V	I _F = 60A
	-	0.87	1.03	V	I _F = 60A, T _J = 175°C
	-	0.93	1.10	V	I _F = 60A, T _J = 125°C
I _R Reverse Leakage Current	-	-	50	μA	V _R = V _R Rated
	-	-	2	mA	T _J = 150°C, V _R = V _R Rated
C _T Junction Capacitance	-	50	-	pF	V _R = 400V
L _S Series Inductance	-	3.5	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ T_J = 25°C (unless otherwise specified)

Parameters	Min	Typ	Max	Units	Test Conditions	
t _{rr} Reverse Recovery Time	-	50	60	ns	I _F = 1A, di _F /dt = 200A/μs, V _R = 30V	
	-	85	-		T _J = 25°C	
	-	145	-		T _J = 125°C	
I _{RRM} Peak Recovery Current	-	8.8	-	A	I _F = 60A V _R = 200V di _F /dt = 200A/μs	
	-	15.4	-			T _J = 125°C
Q _{rr} Reverse Recovery Charge	-	375	-	nC		T _J = 25°C
	-	1120	-			T _J = 125°C

Thermal - Mechanical Characteristics

Parameters	Min	Typ	Max	Units
R _{thJC} Thermal Resistance, Junction to Case			0.70	K/W
R _{thCS} ② Thermal Resistance, Case to Heatsink		0.2		
Wt Weight		5.5		g
		0.2		(oz)
T Mounting Torque	1.2		2.4	N * m
	10		20	lbf.in

② Mounting Surface, Flat, Smooth and Greased

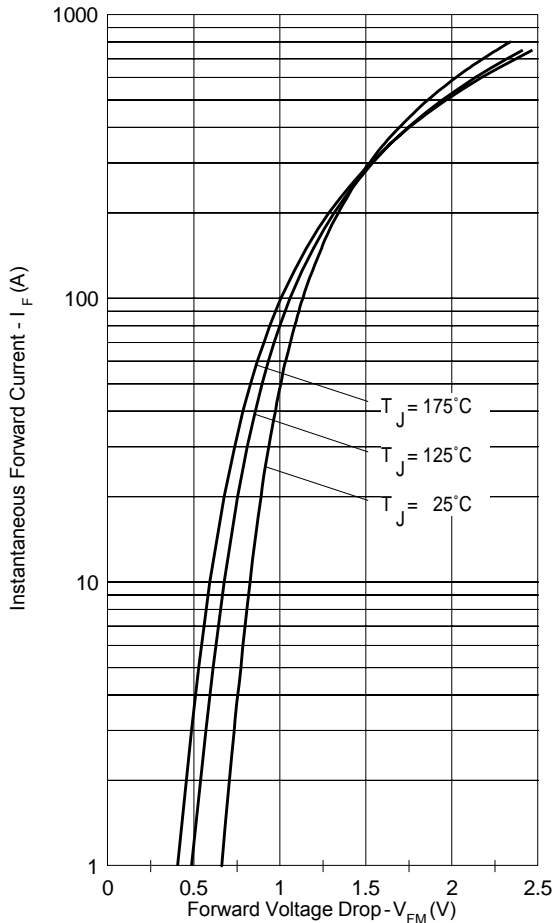


Fig. 1 - Typical Forward Voltage Drop Characteristics

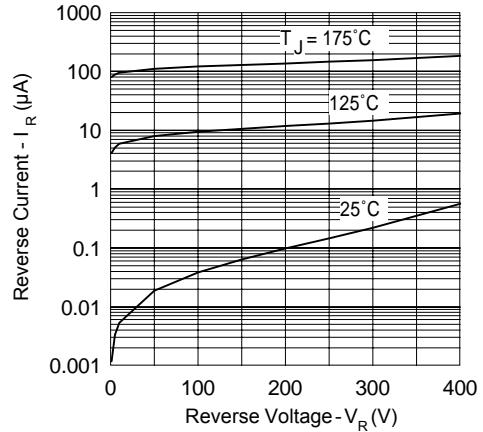


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage

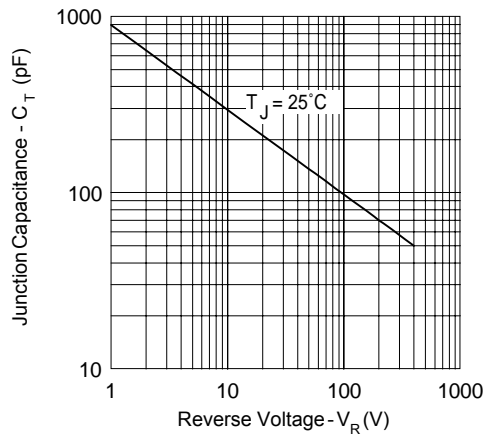


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

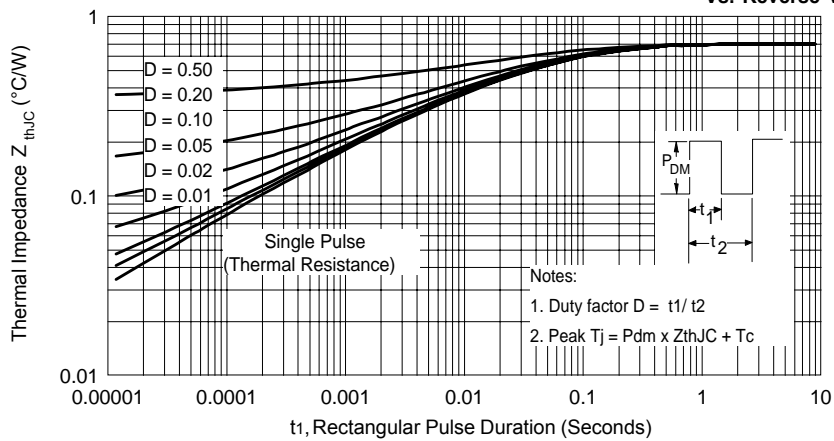


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics

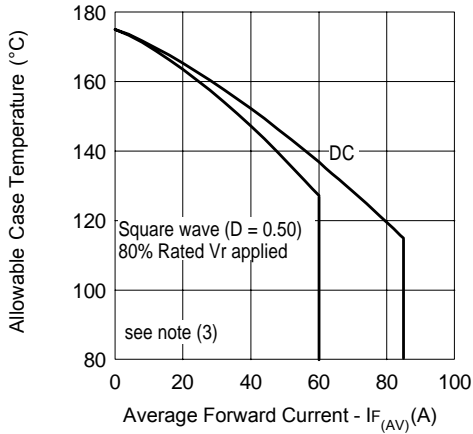


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

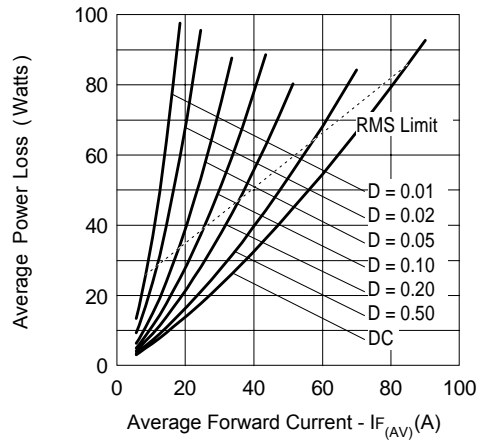


Fig. 6 - Forward Power Loss Characteristics

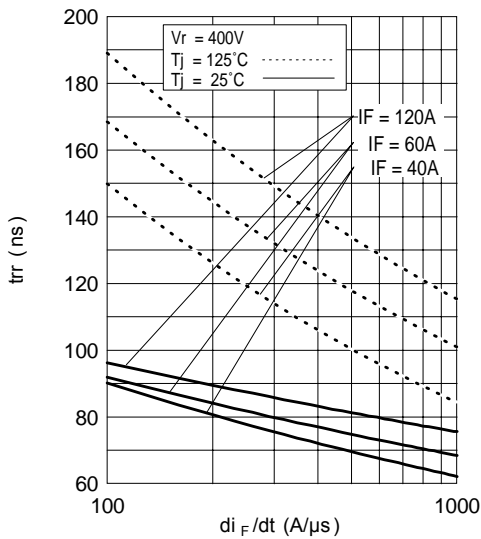


Fig. 7 - Typical Reverse Recovery time vs. di_F/dt

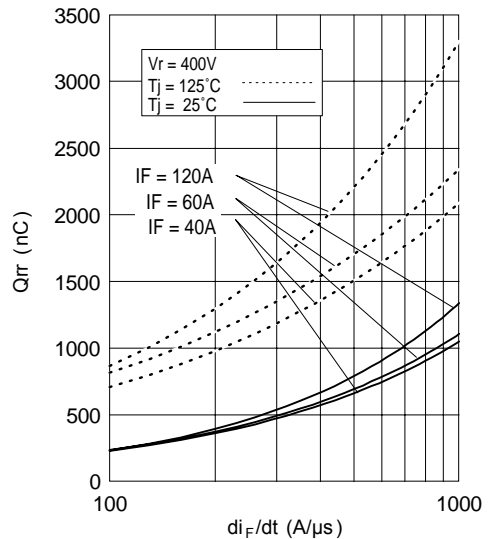


Fig. 8 - Typical Stored Charge vs. di_F/dt

(3) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D); I_R @ V_{R1} = 80\% \text{ rated } V_R$

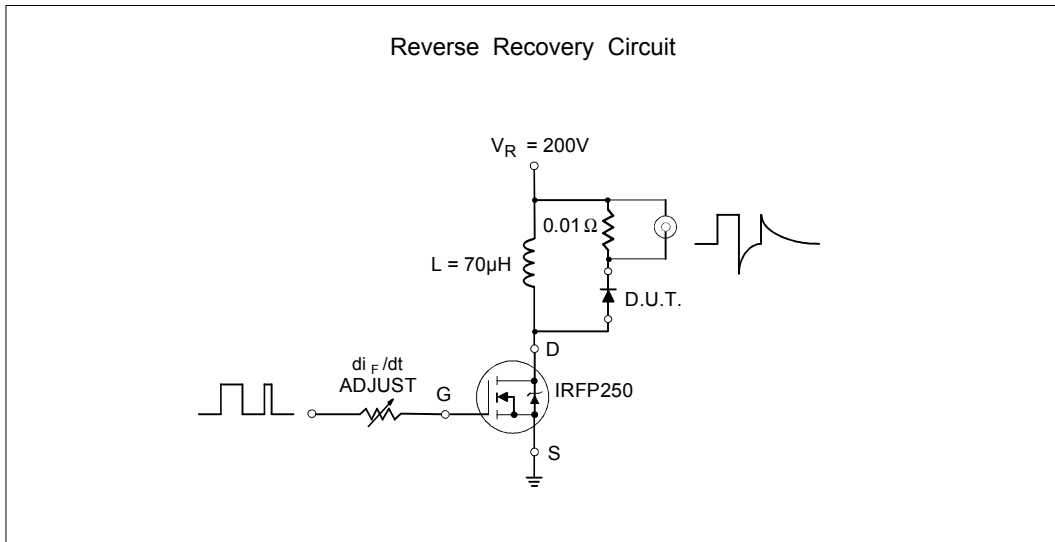


Fig. 9- Reverse Recovery Parameter Test Circuit

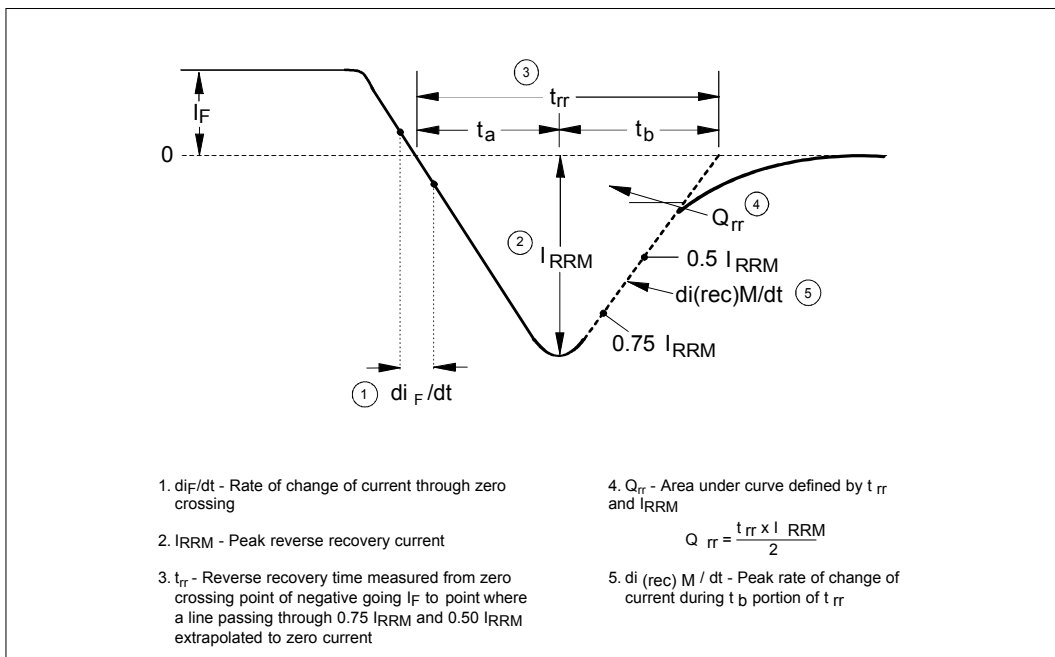
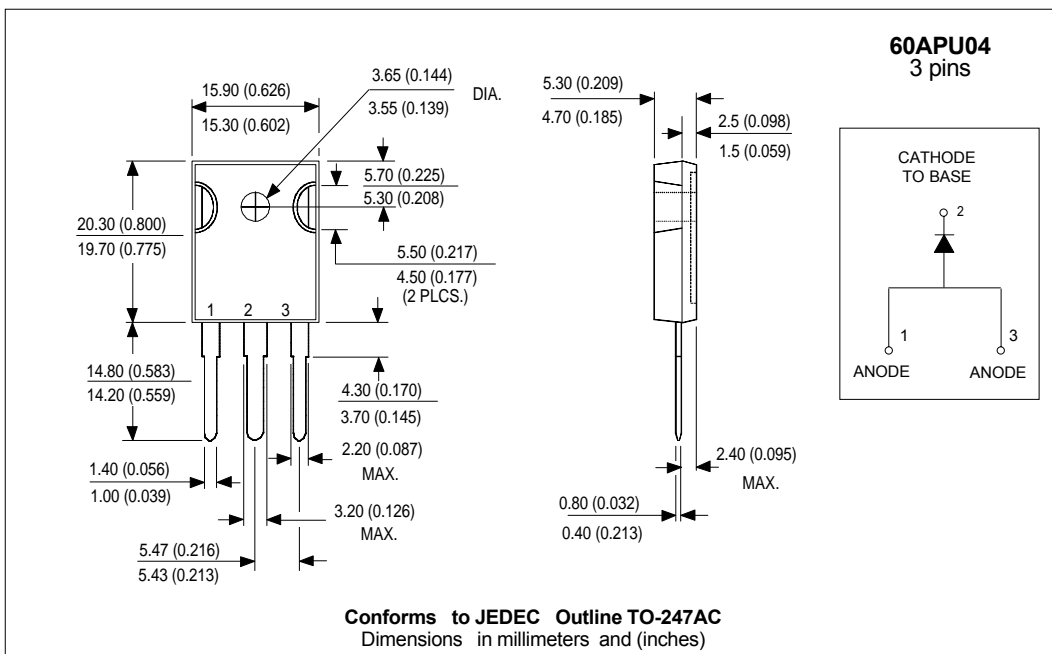
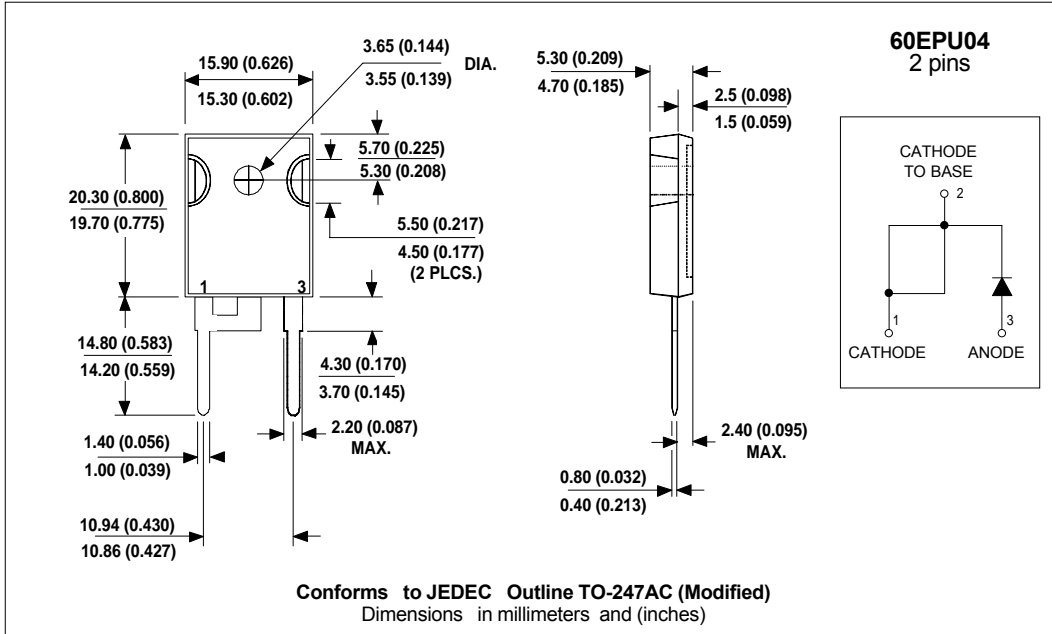
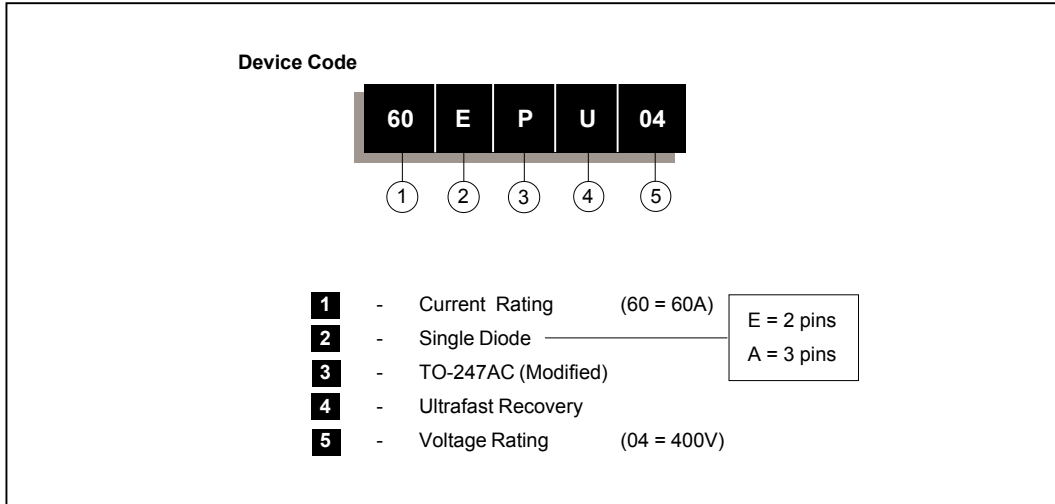


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



Ordering Information Table



Data and specifications subject to change without notice.
 This product has been designed and qualified for Industrial Level.
 Qualification Standards can be found on IR's Web site.